Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.230 inch	es and 0.300 inches
Terminal Length:	
Between 1.000 inch	es and 1.500 inches
Overall Diameter:	
Between 0.085 inch	es and 0.107 inches
Electrode Internall	y-electrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Features Provided	:
Hermetically sealed	case
Semiconductor Ma	iterial:
Silicon	
Voltage Rating In \	/olts Per Characteristic:
100.0 regulator vol	tage
Current Rating Per	Characteristic:
1.00 milliamperes so	purce cutoff current pascal
Maximum Operatir	ng Tempurature Per Measurement Point:
175.0 degrees celsi	us ambient air
Test Data Docume	nt:
81349-mil-s-19500 s	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes co	mmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and p	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	I Quantity:
2 uninsulated wire le	ead
Specification Data	
81349-mil-s-19500/4	463 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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